TOSHIBA Field Effect Transistor Silicon N Channel MOS Type

SSM5N05FU

High Speed Switching Applications

Unit: mm

• Small package

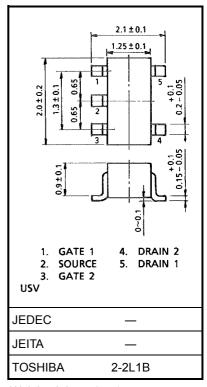
• Low on resistance : R_{on} = 0.8 Ω (max) (@VGS = 4 V) : R_{on} = 1.2 Ω (max) (@VGS = 2.5 V)

• Low gate threshold voltage

Maximum Ratings (Ta = 25°C) (Q1, Q2 Common)

Characteristics		Symbol	Rating	Unit	
Drain-Source voltage		V_{DS}	20	V	
Gate-Source voltage		V_{GSS}	±12	V	
Drain current	DC	I _D	400	mA	
	Pulse	I_{DP}	800		
Drain power dissipation (Ta = 25°C)		P _D (Note1)	300	mW	
Channel temperature		T _{ch}	150	°C	
Storage temperature range		T _{stg}	-55~150	°C	

Note1: Total rating, mounted on FR4 board (25.4 mm \times 25.4 mm \times 1.6 t, Cu Pad: 0.32 mm² \times 5)



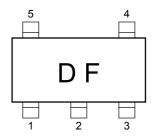
Weight: 6.2 mg (typ.)

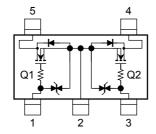
Handling Precaution

When handling individual devices (which are not yet mounting on a circuit board), be sure that the environment is protected against electrostatic electricity. Operators should wear anti-static clothing, and containers and other objects that come into direct contact with devices should be made of anti-static materials.

Marking

Equivalent Circuit (top view)



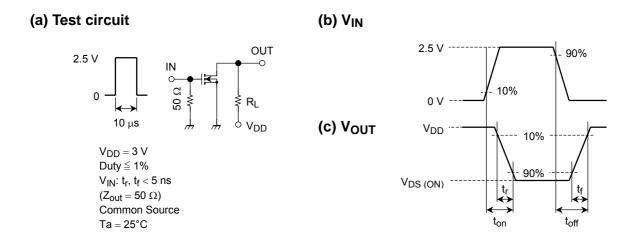


Electrical Characteristics (Ta = 25°C) (Q1, Q2 common)

Characteristics		Symbol	Test Condition	Min	Тур.	Max	Unit
Gate leakage current		I _{GSS}	$V_{GS} = \pm 12 \text{ V}, V_{DS} = 0$	_	_	±1	μΑ
Drain-Source breakdown voltage		V (BR) DSS	$I_D = 1 \text{ mA}, V_{GS} = 0$	20	_	_	V
Drain cut-off current		I _{DSS}	V _{DS} = 20 V, V _{GS} = 0	_	_	1	μΑ
Gate threshold voltage		V _{th}	$V_{DS} = 3 \text{ V}, I_D = 0.1 \text{ mA}$	0.6	_	1.1	V
Forward transfer admittance		Y _{fs}	$V_{DS} = 3 \text{ V}, I_D = 200 \text{ mA}$ (Note2)	350	_	_	mS
Drain-Source ON resistance		R _{DS (ON)}	$I_D = 200 \text{ mA}, V_{GS} = 4 \text{ V}$ (Note2)	_	0.6	0.8	Ω
			$I_D = 200 \text{ mA}, V_{GS} = 2.5 \text{ V}$ (Note2)	_	0.85	1.2	
Input capacitance		C _{iss}		_	22	_	pF
Reverse transfer capacitance		C _{rss}	$V_{DS} = 3 \text{ V}, V_{GS} = 0, f = 1 \text{ MHz}$	_	9	_	pF
Output capacitance		C _{oss}		_	21	_	pF
Switching time	Turn-on time	t _{on}	$V_{DD} = 3 \text{ V}, I_D = 100 \text{ mA},$	_	60	_	ns
	Turn-off time	t _{off}	V _{GS} = 0~2.5 V	_	70	_	

Note2: Pulse test

Switching Time Test Circuit

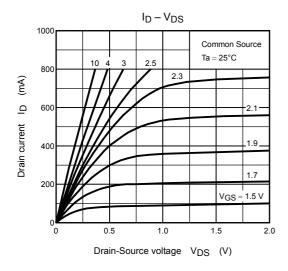


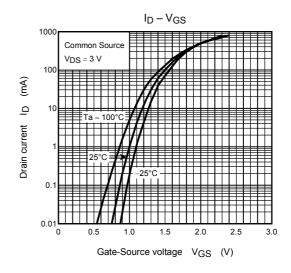
Precaution

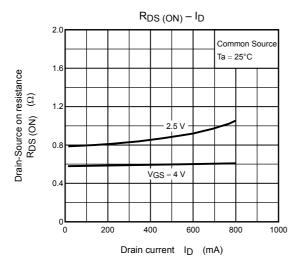
 $V_{th} \ can \ be \ expressed \ as \ voltage \ between \ gate \ and \ source \ when \ low \ operating \ current \ value \ is \ I_D = 100 \ \mu A \ for \ this \ product.$ For normal switching operation, V_{GS} (on) requires higher voltage than V_{th} and V_{GS} (off) requires lower voltage than V_{th} . (Relationship can be established as follows: V_{GS} (off) $< V_{th} < V_{GS}$ (on))

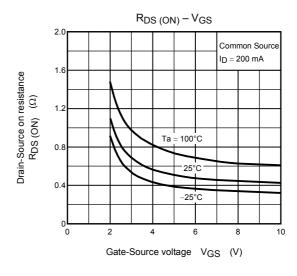
Please take this into consideration for using the device. $V_{\rm GS}$ recommended voltage of 2.5 V or higher to turn on this product.

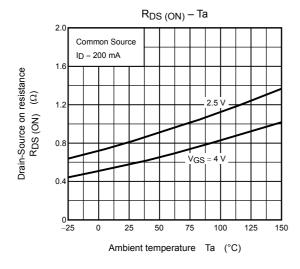
(Q1, Q2 common)

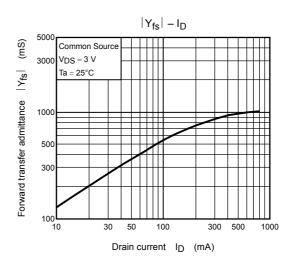






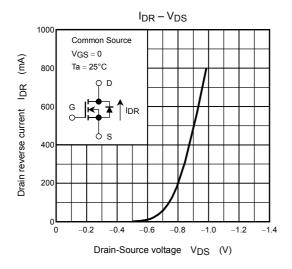


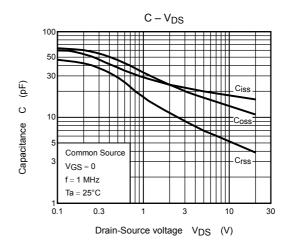


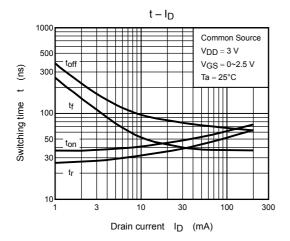


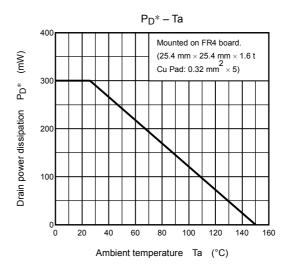
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(Q1, Q2 common)









*: Total rating

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